CDCLD080 CDCLD100 CDCLD120

SURFACE MOUNT SILICON CURRENT LIMITING DIODES





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DESCRIPTION:

The CENTRAL SEMICONDUCTOR CDCLD080 series devices are Current Limiting Diodes (CLDs) specifically designed for applications requiring a constant current over a wide voltage range. The series is designed with a unique process that holds regulator current constant over temperature excursions (zero temperature coefficient). The devices are available in the thermally efficient DPAK package outline.

MARKING: FULL PART NUMBER

FEATURES:

- Zero temperature coefficient
- High regulator currents available
- Industry standard thermally efficient DPAK

MAXIMUM RATINGS: (T_A=25°C unless otherwise noted)

	CDCLD080							
	SYMBOL	CDCLD100	CDCLD120	UNITS				
Peak Operating Voltage	POV	50	45	V				
Peak Operating Voltage (T _C =122°C)	POV		50	V				
Power Dissipation (Note 1)	PD	6.2	25	W				
Power Dissipation (T _C =35°C) (Note 1)	PD	28.	75	W				
Thermal Resistance	ΘJC	4.0		°C/W				
Operating and Storage Junction Temperature	TJ, Tstg	-55 to +150		°C				

Note 1: Mounted on 900mm² 4-layer PCB with 2-ounce copper traces.

ELECTRICAL CHARACTERISTICS: (T_A=25°C)

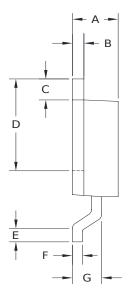
Туре	Regulator Current (tp=4.5ms) I _P @ V _T =5.0V			Maximum Limiting Voltage (tp=5.0ms) V _L @ 0.8 x Ip MIN	
	MIN mA	NOM mA	MAX mA	v	
CDCLD080	72	80	88	1.8	
CDCLD100	85	100	115	2.0	
CDCLD120	102	120	138	2.0	





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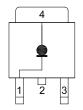
DPAK CASE - MECHANICAL OUTLINE

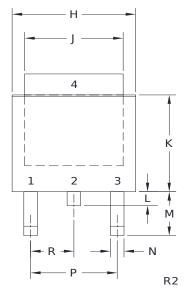


LEAD CODE:

- 1) Cathode
- 2) Anode
- 3) No Connection
- 4) Anode
- Pin 2 is common to the tab (4)

MARKING: FULL PART NUMBER





DIMENSIONS								
	INCHES		MILLIMETERS					
SYMBOL	MIN	MAX	MIN MAX					
A	0.083	0.108	2.10	2.75				
В	0.016	0.035	0.40	0.89				
С	0.035	0.063	0.89	1.60				
D	0.203	0.228	5.15	5.79				
E	0.020	-	0.51	-				
F	0.016	0.024	0.40	0.60				
G	0.061		1.55					
н	0.248	0.268	6.30	6.81				
J	0.195	0.217	4.95	5.50				
К	0.209	0.245	5.30	6.22				
L	0.033		0.83					
М	0.090	0.115	2.30	2.91				
N	0.012	0.045	0.30	1.14				
P	0.180		4.60					
R	0.090		2.30					

DPAK(REV:R2)

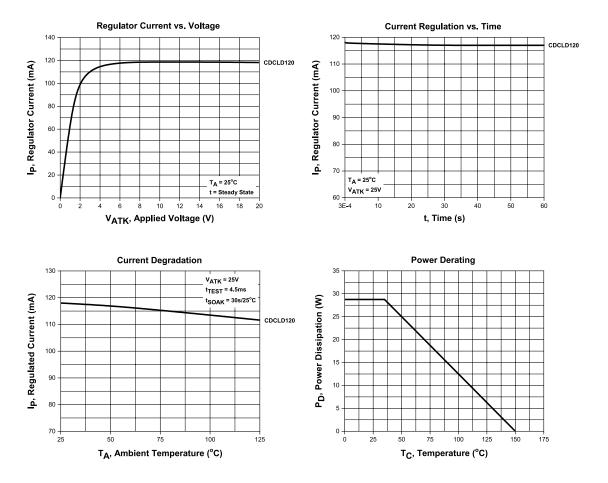
R7 (18-August 2023)



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TYPICAL ELECTRICAL CHARACTERISTICS





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TYPICAL APPLICATIONS

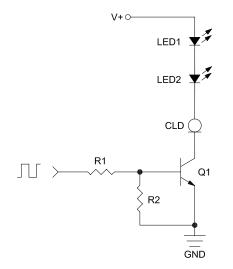


Figure 1. CLDs can be used to limit the current flowing through LED strings. Their dynamic performance make them an excellent replacement for current limiting resistors, as they allow for continuous current regulation regardless of input voltage. LED strings like this are commonly used in dimming lighting systems. By using a PWM input to control the transistor, the LED luminosity can be controlled by extending or decreasing the pulse width, allowing for control over the brightness of the LED.





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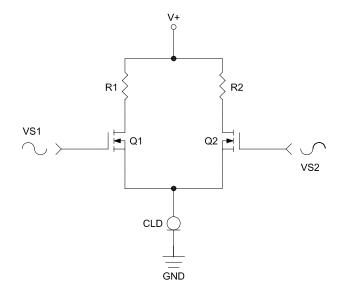


Figure 2. When designing differential amplifiers, it is essential to use a high impedance tail resistor to control both differential and common mode function. For differential signals, the tail resistor effectively splits the current amongst the transistors. This ensures proportional current increase and decrease between the transistors. The high impedance drives down the common mode gain and increases the common mode rejection ratio, thus yielding a more ideal amplifier. Ideally, an infinite impedance current source would be used in place of the tail resistor. While the ideal current source doesn't exist, CLDs serve as an excellent replacement for the tail resistor and also perform much like an active current source, both regulating the circuit to a constant current and presenting a large tail impedance. This yields a larger CMRR than using a high impedance tail resistor would.

OUTSTANDING SUPPORT AND SUPERIOR SERVICES

PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- · Consolidated shipping options

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities

ss your design challenges.

· Custom product packing

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits

Custom bar coding for shipments

Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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